NSN 5961-01-110-3045

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-110-3045 **Inclosure Material:** Metal **Overall Length:** Between 0.259 inches and 0.281 inches **Overall Diameter:** Between 0.395 inches and 0.405 inches **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 repetitive peak reverse voltage, peak total value and 120.0 working peak reverse voltage, peak total value and 70.0 reverse voltage, total rms **Current Rating Per Characteristic:** 22.00 amperes forward current, average absolute and 400.00 amperes source cutoff current peak **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0